

Dynamics and current fluctuations for AC forced charge shuttle

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F.P. Phys. Rev. B **69**, 245409 (2004),

F.P. and R. Fazio, Phys. Rev. Lett. **94**, 036806 (2005),

F.P. and R. Fazio, New Journal of Physics, special issue on NEMS (2006)

A new mechanism of electron transfer: charge Shuttle

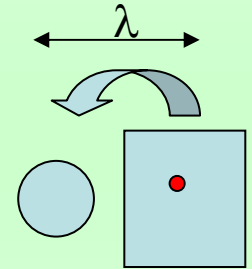
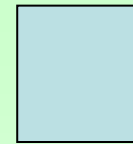
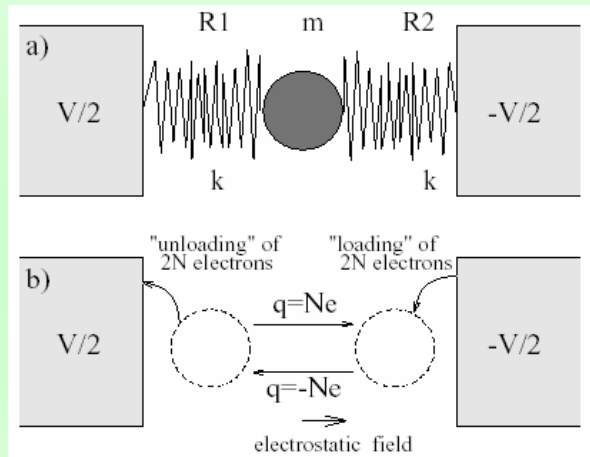
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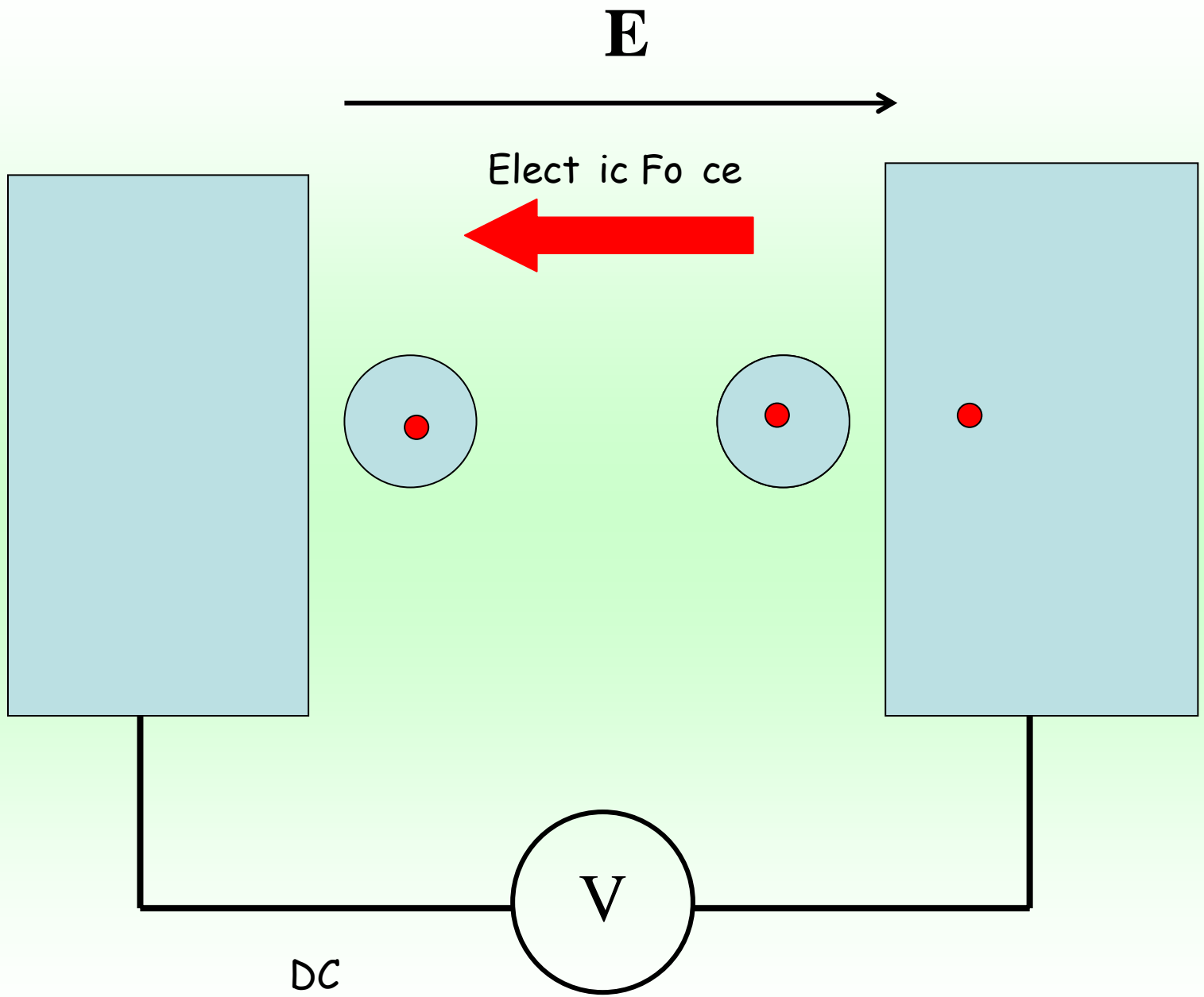
Shuttle Mechanism for Charge Transfer in Coulomb Blockade Nanostructures

L. Y. Gorelik,^{1,2} A. Isacsson,¹ M. V. Voinova,^{1,3} B. Kasemo,¹ R. I. Shekhter,¹ and M. Jonson¹



$$\text{Tunnelling resistance: } R(x) = R_0 e^{-x/\lambda}$$

See also Isacsson *et al* Physica (1998)



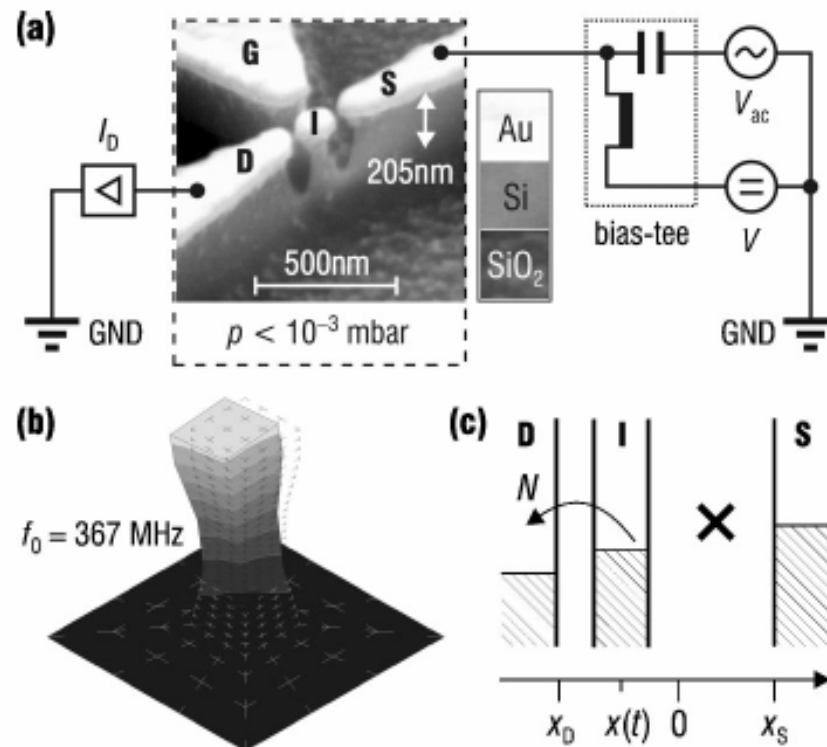
Silicon nanopillars for mechanical single-electron transport

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AC forced
charge shuttle

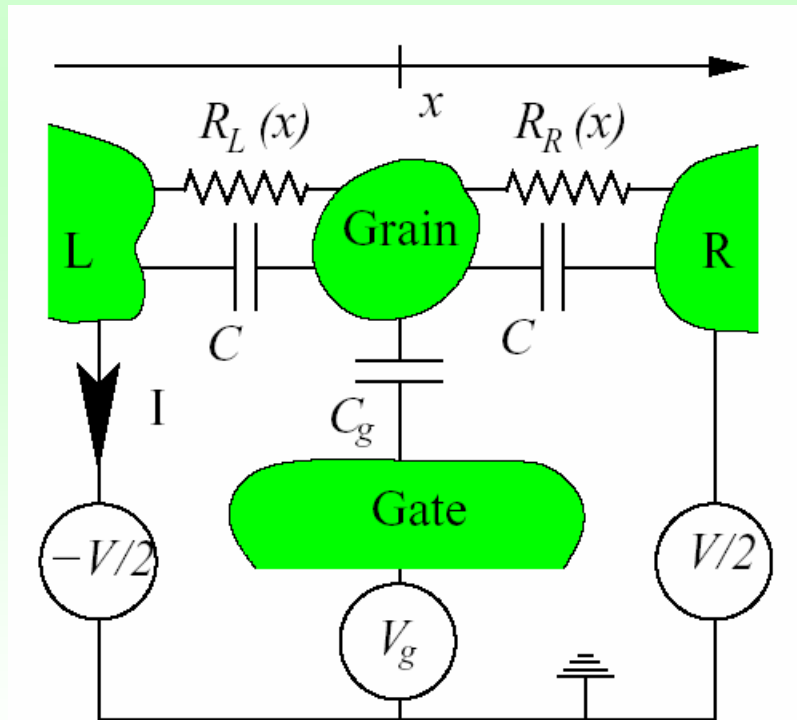
F.P. and R. Faio, Phys. Rev. Lett. (2005)

Classical description of the island:

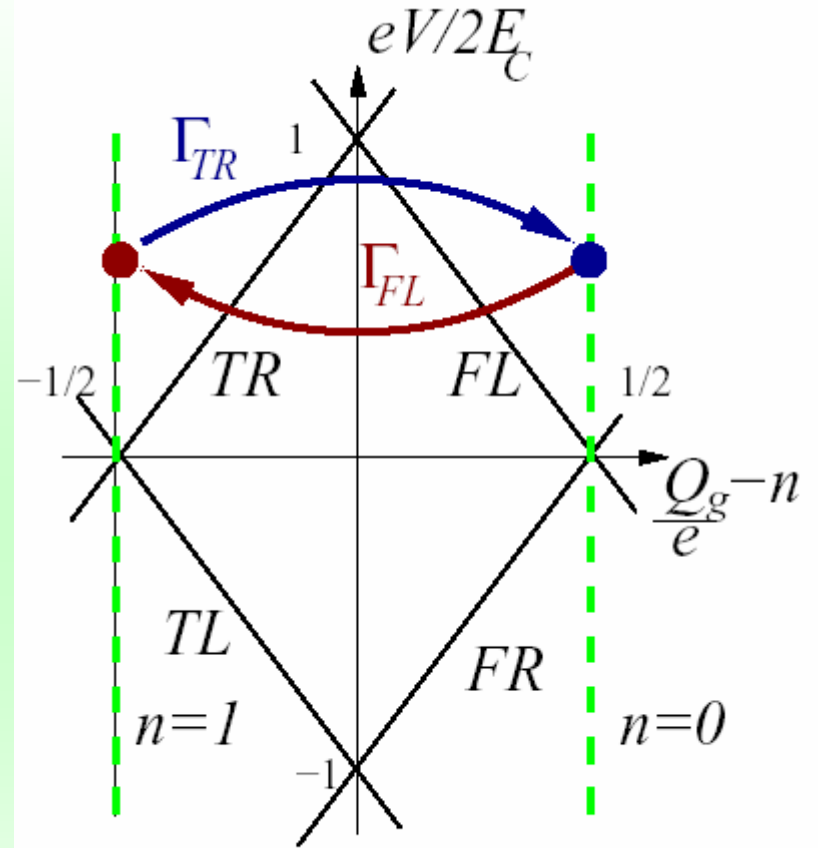
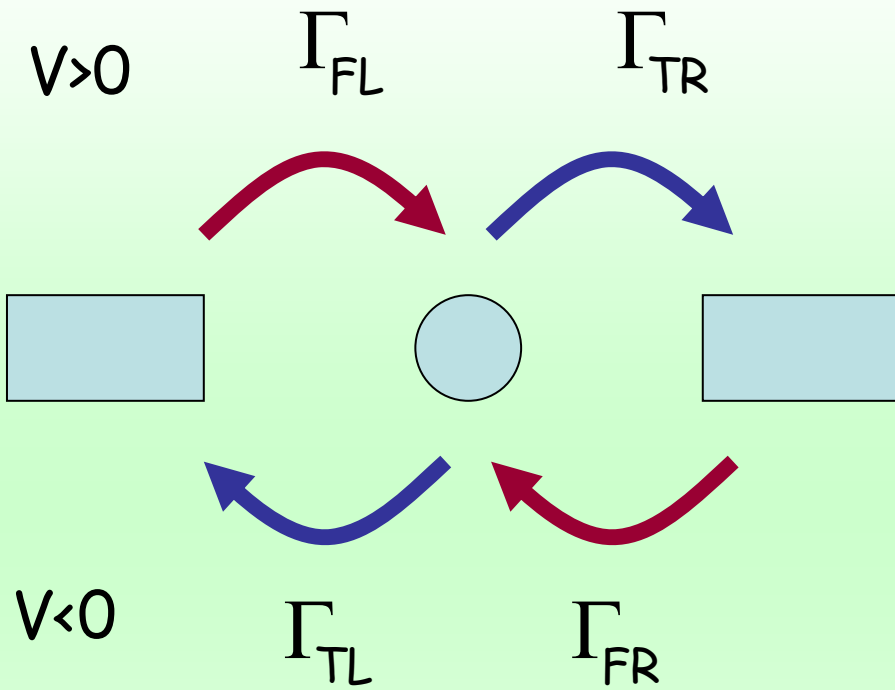
$$\ddot{x} = -\omega_o^2 x - \gamma \dot{x} + \frac{eV(t)}{Lm} n(t)$$

The force depends on the stochastic variable $n(t)$

Simple case, $n=0,1$. SET scheme



Coulomb blockade scheme



No memory of the environment

Allows to use $\Gamma(t) = \Gamma[x(t)]$

$$\hbar\omega \ll k_B T \ll E_C \sim eV$$

The motion of the gain influences the rates:

$$\Gamma_{FL}(t) = \frac{|eV(t)|}{4E_C} \Gamma_L[x(t)] \Theta[V(t)]$$

$$\Gamma_{L/R}(x) = [R_{L/R}(x)C]^{-1}$$

$$R_{R/L}(x) = R_{L/R} e^{\mp x/\lambda}$$

We find a Rectification effect for the shuttle

For asymmetric resistances rectification of the current through the stochastic occupation of the grain

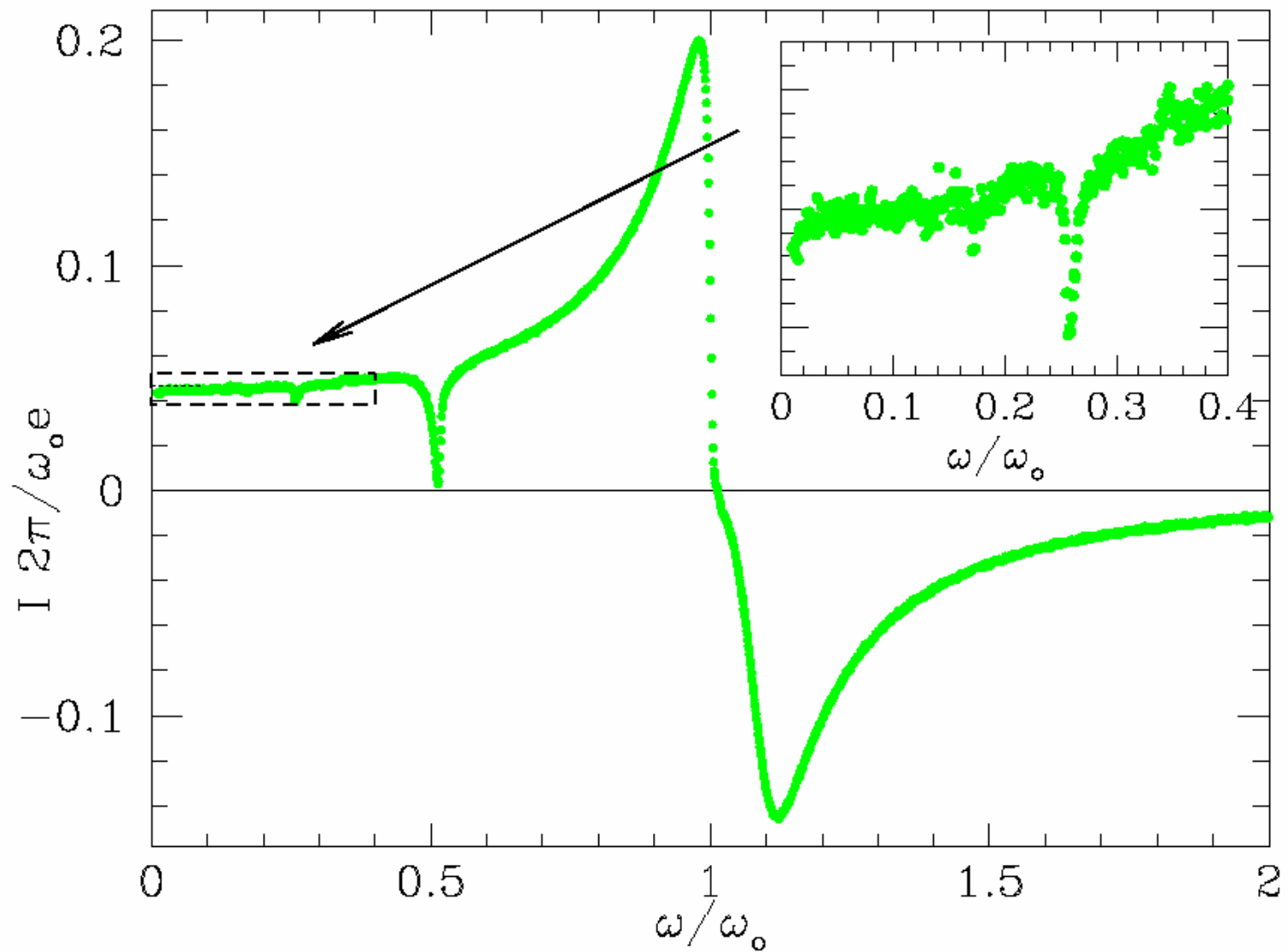
Evidence by Monte Carlo simulations

We consider asymmetric contacts (eg $R_R = 10 R_L$) and AC voltage bias

- ◇ analytical evolution of the grain between two tunneling events
- ◇ tunneling events statistics determined by $\Gamma[x(t)]$
- ◇ each simulation 10^6 tunneling events

We let the voltage oscillate between $-E_c/e$ and $+E_c/e$ (only $n=\pm 1$)

Rectified current



Simplifying approximation: mechanical force \gg electric force

$$\epsilon = \frac{eE}{\lambda k} = \frac{\text{Electric Force}}{\text{Elastic Force}} \ll 1$$

The harmonic oscillation is only **slowly** modified by the electric field

stochastic fluctuations of the position are then small

$$n(t) \rightarrow \langle n(t) \rangle = P_1(t)$$

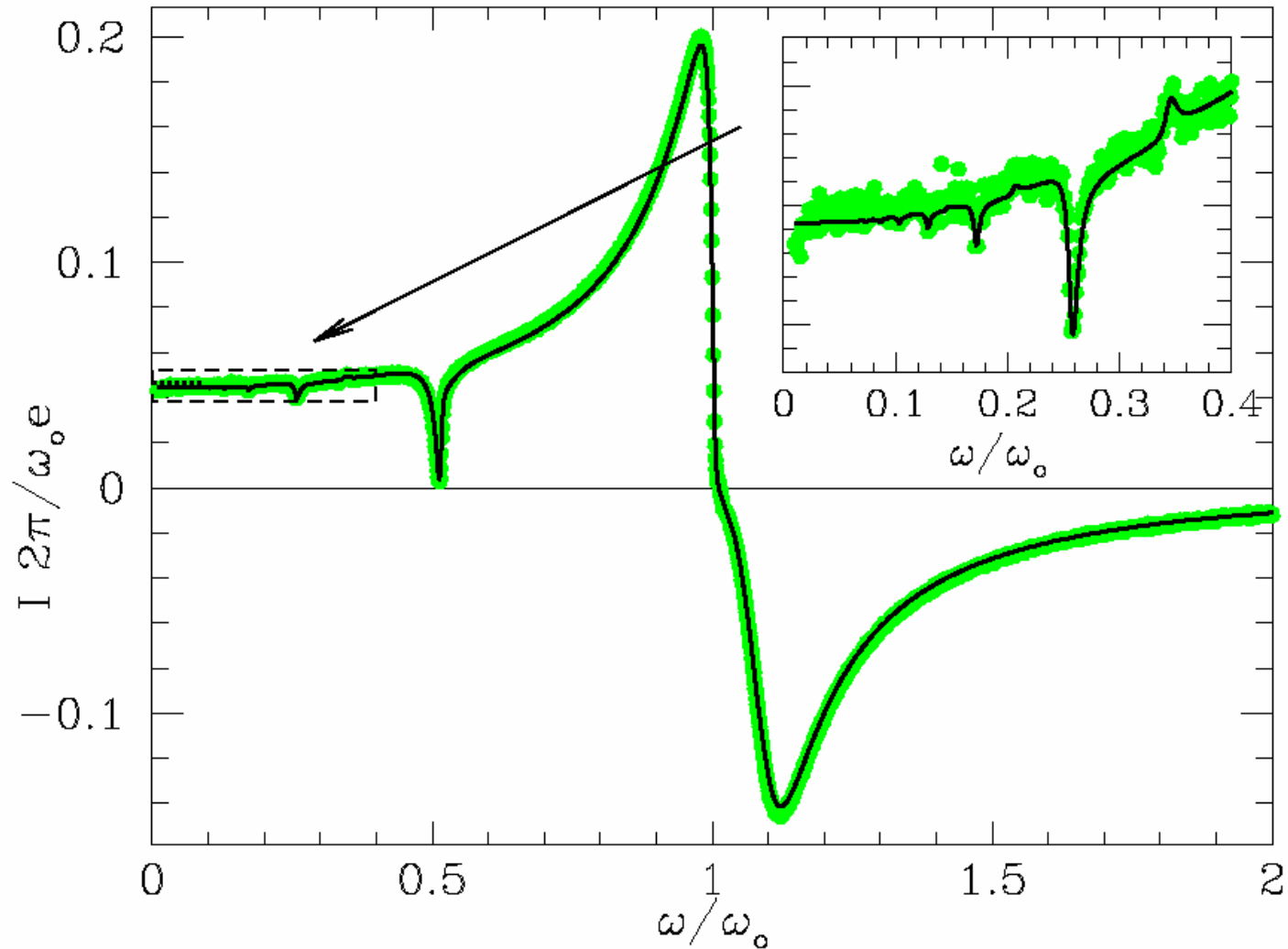
Master equation for P_1

$$\frac{dP_1}{dt} = -\Gamma_1[x(t)] P_1(t) + \Gamma_2[x(t)]$$

average current

$$I(t)/e = [1 - P_1(t)]\Gamma_{FL}(t) - P_1(t)\Gamma_{TL}(t)$$

Black line: **ave age app oximation**



he e $\epsilon=0.5$

Adiabatic limit $\omega \ll \omega_0$ and $\epsilon \omega_0/\gamma < \text{shuttling}$

The occupation of the g ain will be one that satisfies both stationary master equation and equilibrium of forces

$$P_1(x_e) = \Gamma_2(x_e)/\Gamma_1(x_e)$$

$$x_e = \frac{eV}{Lk} P_1(x_e) = \epsilon \lambda \frac{eV}{2E_C} P_1(x_e)$$

by perturbation theory in ϵ

$$I_a(\omega \ll \omega_0) = \epsilon \frac{V_0 e^2}{32 E_C} \frac{\Gamma_L \Gamma_R (\Gamma_L - \Gamma_R)}{(\Gamma_R + \Gamma_L)^2}$$

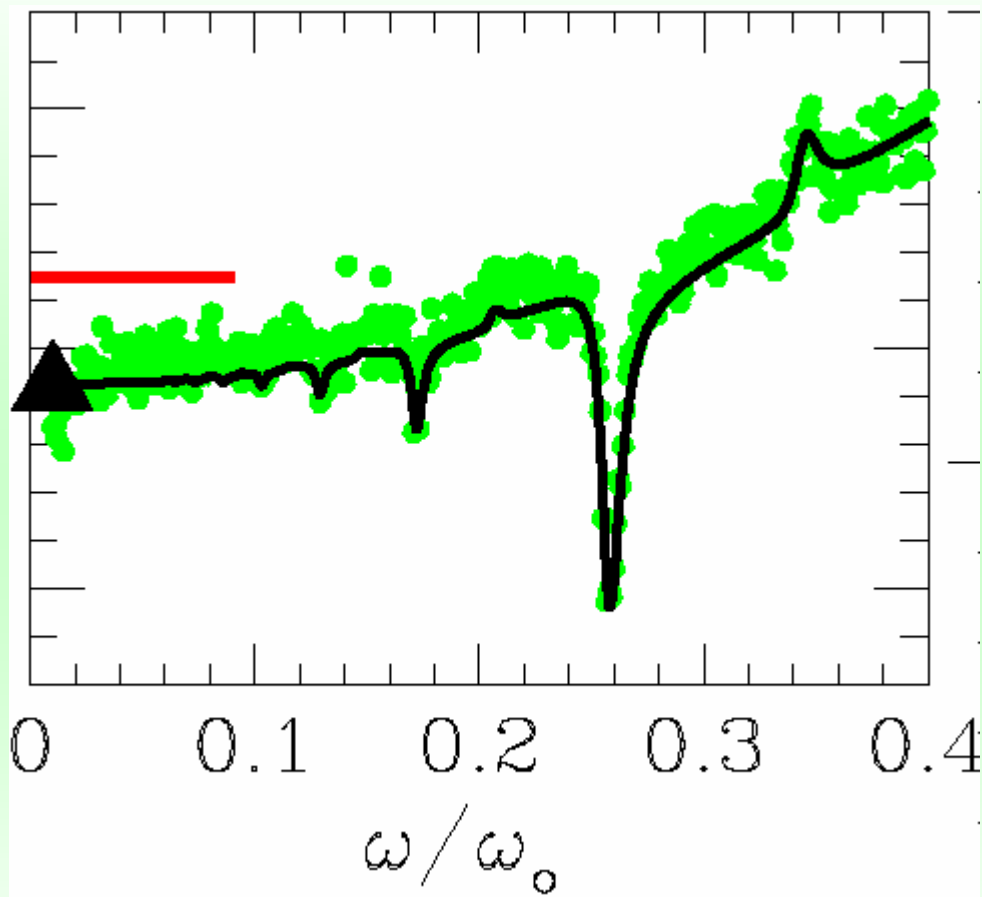
$I(V) \neq I(-V)$ due to the motion of the g ain

this can be a very simple and robust way of testing mechanical motion

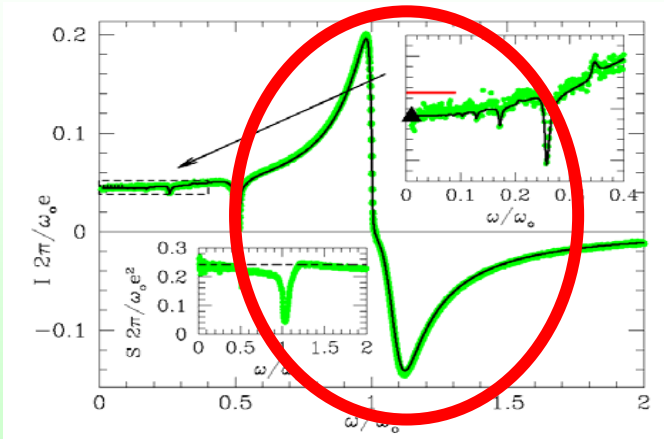
adiabatic result

for $\varepsilon \ll 1$

adiabatic
numerical



Main resonance

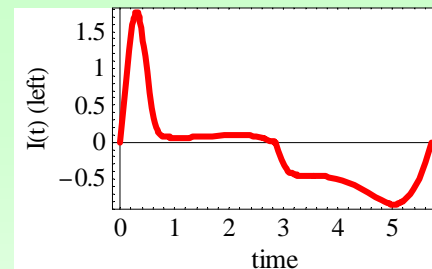
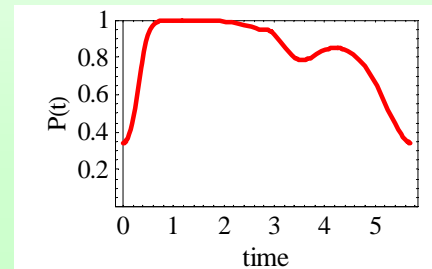
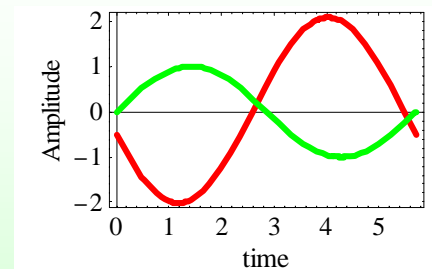
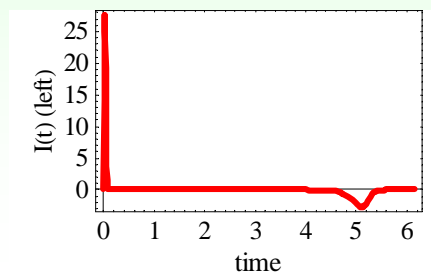
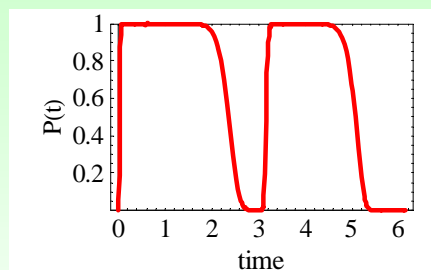
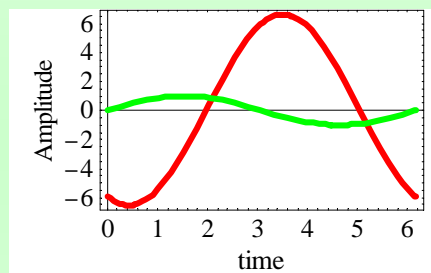
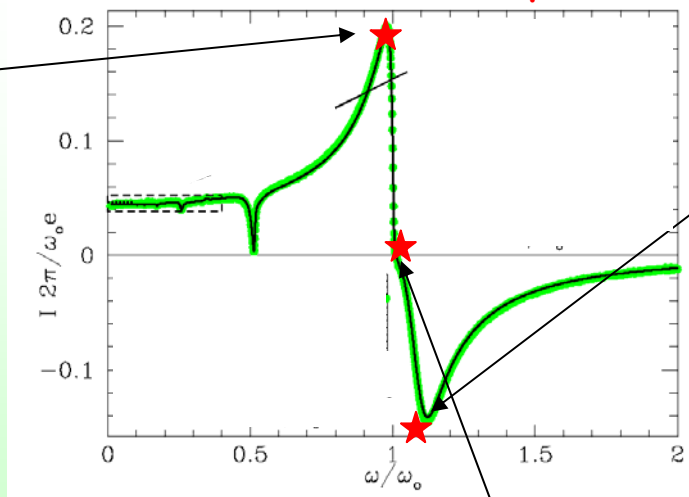
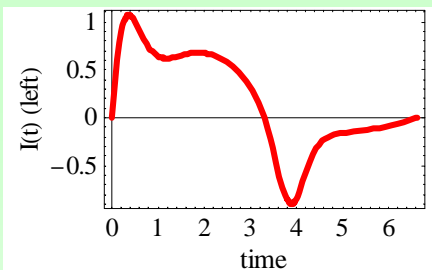
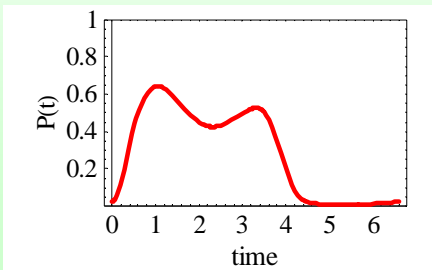
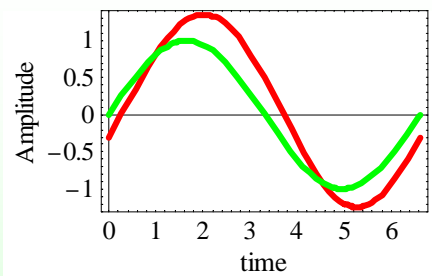


The frequency dependence can be understood in terms of the standard phase shift around a resonance

$$\phi(\omega) = \arctan[\omega\gamma/(\omega^2 - \omega_0^2)] \quad x(t) = A \sin[\omega t - \phi(\omega)]$$

Solving the master equation with periodic boundary conditions and this form of $x(t)$ one reproduces the shape of the resonance

Phase shift current dependence



Positive current

$$\omega/\omega_0 = 0.95$$

$$\phi \approx 0$$

~ vanishing I

Negative current

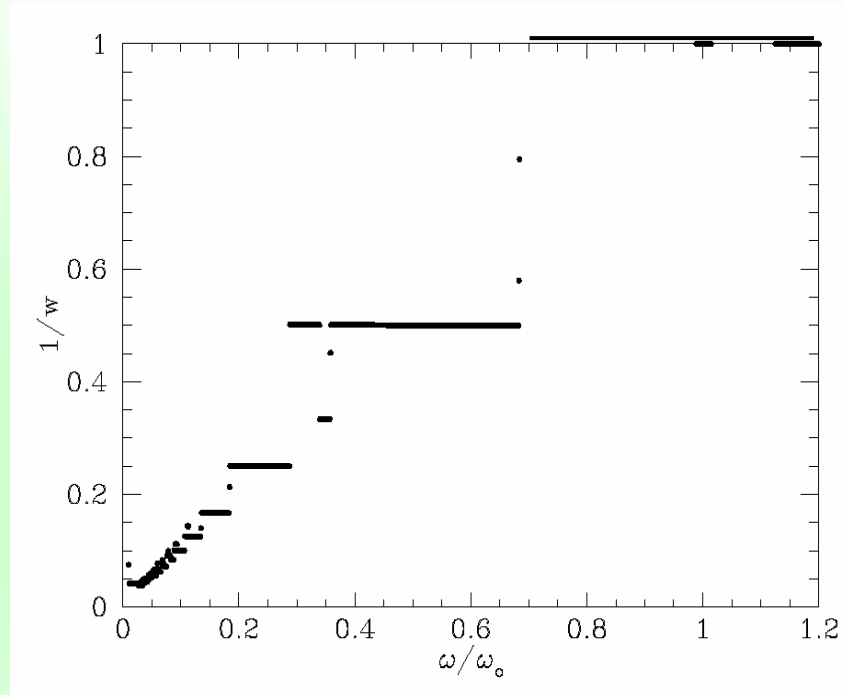
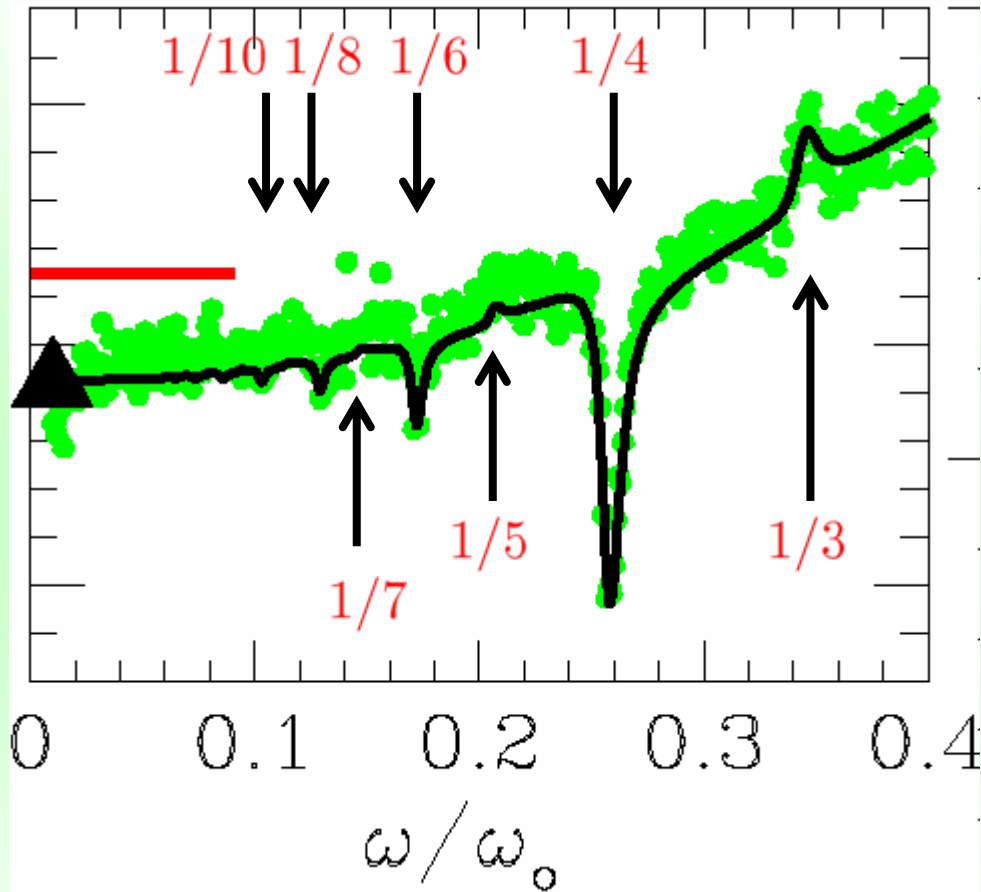
$$\omega/\omega_0 = 1.1$$

$$\phi \approx \pi$$

$$\phi \approx \pi/2$$

$$\omega/\omega_0 = 1.02$$

Devil's staircase case of frequencies

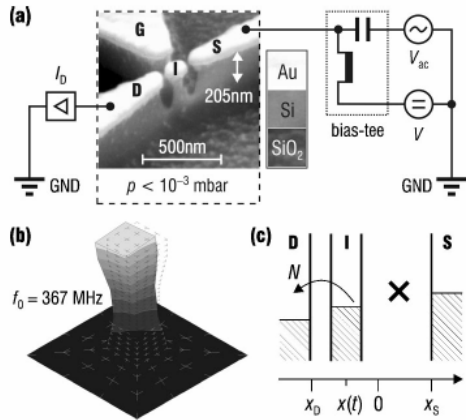


non-linear stochastic force lead to frequency locking

$$\text{for } \omega = \omega_0/n$$

Recent experiment observed the main resonance

D. Sheible and R. Blick APL 2004

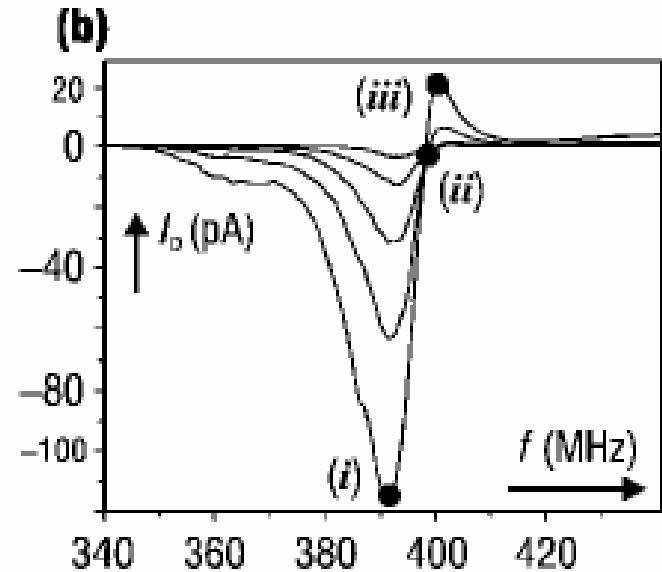
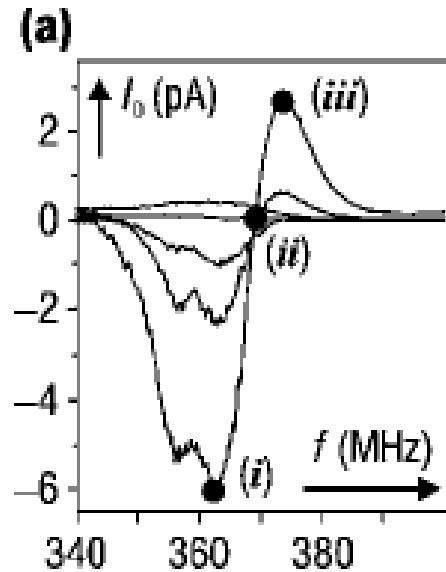


Not in Coulomb regime

Room temperature and $E_C \approx 80$ K

But main feature present

Structures at low frequencies present (private communication)



Instability in presence of an AC drive

Fourier expansion (without forcing)

$$x(t)/\lambda = \sum_{\nu=1}^{\infty} [A_{\nu} \sin(\nu\omega t) + B_{\nu} \cos(\nu\omega t)] + B_0/2$$

$$\sum_n P_n(t)n = \sum_{\nu=1}^{\infty} [C_{\nu} \sin(\nu\omega t) + D_{\nu} \cos(\nu\omega t)] + D_0/2$$

$$\begin{pmatrix} A_{\nu} \\ B_{\nu} \end{pmatrix} = \frac{\epsilon}{\left(\frac{\nu^2\omega^2}{\omega_o^2} - 1\right)^2 + \left(\frac{\eta\nu\omega}{\omega_o}\right)^2} \begin{pmatrix} 1 - \nu^2\omega^2/\omega_o^2 & \eta\nu\omega/\omega_o \\ -\eta\nu\omega/\omega_o & 1 - \nu^2\omega^2/\omega_o^2 \end{pmatrix} \begin{pmatrix} C_{\nu} \\ D_{\nu} \end{pmatrix}$$

At resonance:

$$\omega_R^2/\omega_o^2 \approx 1 - \eta C_1/D_1$$

Resonance shift

$$\eta A_1 = \epsilon D_1(A_1)$$

Energy balance

For small A_1/λ : analytical expressions

$$C_1/\lambda = -a \frac{2\tilde{\Gamma}}{1 + 4\tilde{\Gamma}^2} \left[1 + \frac{a^2}{4} \frac{1 - 4\tilde{\Gamma}^2}{1 + 4\tilde{\Gamma}^2} \right] \quad D_1/\lambda = a \frac{\tilde{\Gamma}}{1 + 4\tilde{\Gamma}^2} \left[1 + \frac{a^2}{4} \frac{1 - 12\tilde{\Gamma}^2}{1 + 4\tilde{\Gamma}^2} \right]$$

Instability for

$$\epsilon > \epsilon_c = \eta(1 + 4\tilde{\Gamma}^2)/\tilde{\Gamma}$$

In presence of the AC drive:

$$\epsilon \rightarrow \epsilon[1 + \alpha \sin(\omega t + \delta)]$$

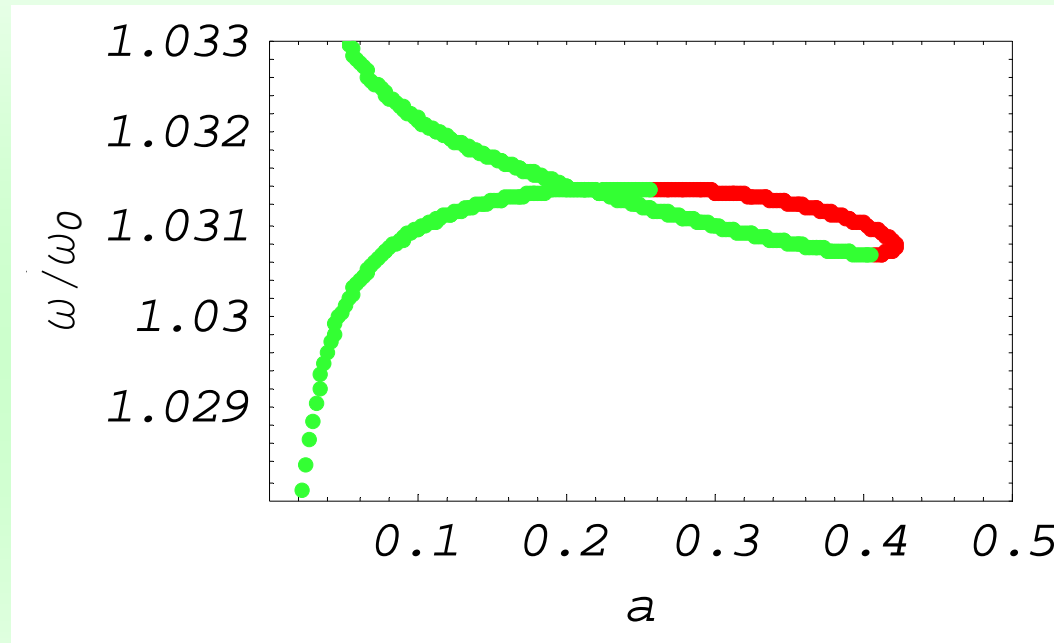
$$P_n(t) \rightarrow P_n(t)[1 + \alpha \sin(\omega t + \delta)]$$

Slow motion of $\delta(t)$ and $a(t) = A_1(t)/\lambda$

$$\frac{d}{d(\omega t)} \begin{pmatrix} a \\ \delta \end{pmatrix} \approx \begin{pmatrix} 1/2 & \eta/4 \\ -\eta/4a & 1/2 \end{pmatrix} \cdot \begin{pmatrix} -\eta a + \epsilon D_1/\lambda \\ a(\omega^2/\omega_0^2 - 1) + \epsilon C_1/\lambda \end{pmatrix}$$

Evolution of the stability

~~110035~~



Stationary UNSTABLE points

Stationary STABLE points

Stationary UNSTABLE points

Stationary STABLE points

$$\tilde{\Gamma} = 1, \eta = 0.03, \alpha = 0.002$$

Full counting statistics

F. P. Phys. Rev. B (2004)

F.P. and R. Faio, New Journal of Physics (2006)

Transport described by a master equation
 one can obtain the FCS in the following way:

Bagrets and Nazarov PRB 2003

$$e^{-S_{to}(\chi)} = \langle q | T \exp \left\{ - \int_0^t \hat{L}_\chi(t') dt' \right\} | p(0) \rangle \quad |q\rangle \equiv \{1, 1\}$$

$$\hat{L}_\chi(t) = \begin{pmatrix} \Gamma_L(t) & -\Gamma_R(t) \\ -\Gamma_L(t)e^{i\chi} & \Gamma_R(t) \end{pmatrix}$$

We assume **perfect periodic** motion $x(t) = \lambda \sin(\omega t)$

$$e^{-S_N(\chi)} = \langle q | \hat{A}^N | p(0) \rangle$$

$$\hat{A} = T \exp \left\{ - \int_0^{2\pi} \hat{L}_\chi(\phi') d\phi' \right\}$$

For $N \rightarrow \infty$ the largest (in modulus) eigenvalue of \hat{A} survives $\lambda_M(\chi)$

$$S_N(\chi) \approx -N \ln[\lambda_M(\chi)]$$

Full Counting Statistics (analytic)

$$e^{-S_N/N} = \frac{e^{-4\tau}}{2} [(1 - 2\alpha)(y^2 - 1) + 2y \sinh(4\tau y) + (1 + 2\alpha + (1 - 2\alpha)y^2) \cosh(4\tau y)]$$

$$\tau \approx \Gamma/a$$

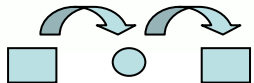
Trinomial distribution for $\tau \ll 1$

$$e^{-S_N(\chi)} = [\beta_0 + \beta_1 e^{i\chi} + \beta_2 e^{2i\chi}]^N$$

$$\begin{cases} \beta_0 = 2\alpha(1 - 4\tau + 8\tau^2) \\ \beta_1 = 1 - 2\alpha(1 - 4\tau + 4\tau^2) - 4\tau^2 \\ \beta_2 = 4\tau^2(1 - 2\alpha) \end{cases}$$

Maximum probability of transferring 1 electron

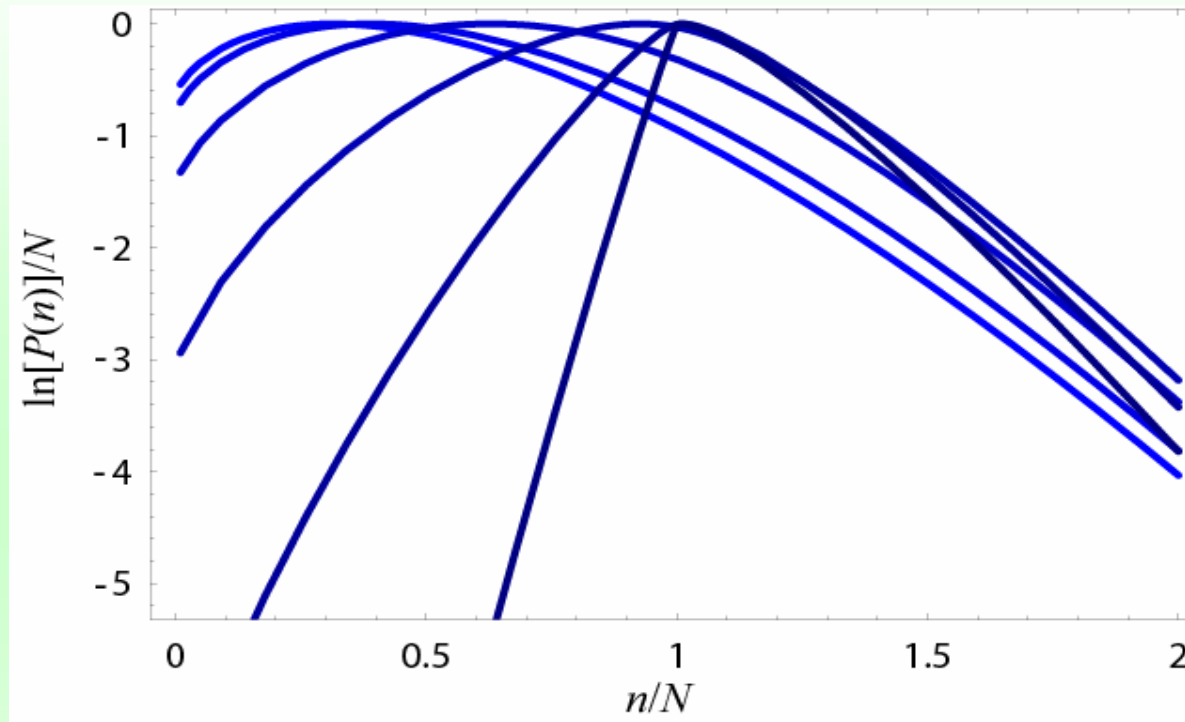
Probability of no transfer at all controlled by α



Probability of transfer of 2 electrons controlled by τ

Numerical results:

Full counting statistics for $\Gamma=0.1$



F.P. Phys. Rev. B (2004)

Related papers

Full Counting Statistics of Cooper Pair Shuttling

A. Romito and Yu. V. Nazarov, Phys. Rev. B. 2004

Full counting statistics of nano-electromechanical systems

C. Flindt, T. Novotny, and A.-P. Jauho, Europhys. Lett. 2005

Full Counting Statistics for the AC forced shuttle

The same approach can be used
In the adiabatic limit simple analytical results

$$S_N(\chi)/N = \int_0^{2\pi/\omega} \lambda_1(\chi, t) dt$$

First four cumulants:

$$C_1 = \gamma \epsilon \frac{\pi}{4} \beta (1 - \beta^2)$$

$$C_2 = \gamma (1 - \beta^2) \left[(1 + \beta^2) - \epsilon \frac{\pi}{8} \beta^2 (1 - 3\beta^2) \right]$$

$$C_3 = \gamma \epsilon \frac{\pi}{16} \beta (1 - \beta^2) (1 - 12\beta^2 + 15\beta^4)$$

$$C_4 = \gamma \frac{(1 - \beta^2)}{4} \left[(1 + \beta^2 - 9\beta^4 + 15\beta^6) - \epsilon \frac{\pi}{8} \beta^2 (1 - 39\beta^2 + 135\beta^4 - 105\beta^6) \right]$$

Adiabatic parameter

$$\gamma = eV_o \Gamma / (4E_C \omega) \gg 1$$

Asymmetry parameter

$$\beta = \frac{\Gamma_L(0) - \Gamma_R(0)}{\Gamma_L(0) + \Gamma_R(0)}$$

Conclusions

- The **cha ge shuttle** fo ced by an AC voltage shows a **ectification** effect
- The **non-linea ity** is due to the stochastic occupation of the g ain
Int insic not dependent on the mechanical esponse
- The **development of the instability** in p esence of an AC field lead to strong non-linea ities in the esponse that can be studied expe imentally
- **Cu ent fluctuations** give insight on the dynamics of the device

Pe spective: Quantum AC fo ced shuttle

In this di ection: quantum noise in AC biased chaotic cavities:

D. Bag ets and F. Pistolessi, cond-mat/June06